

#### **Features**

- High Density Cell Design For Low R<sub>DS(ON)</sub>
- · Trench Power LV MOSFET Technology
- · Excellent Package for Heat Dissipation
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# N-CHANNEL MOSFET

#### **Maximum Ratings**

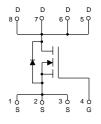
- Operating Junction Temperature Range : -55°C to +175°C
- Storage Temperature Range: -55°C to +175°C
- Maximum Thermal Resistance: 7.5°C/W Junction to Case<sup>(Note 2)</sup>

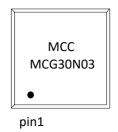
Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Volltage		V <sub>GS</sub>	±20	V
Continuous Drain Current	T <sub>C</sub> =25°C	- I <sub>D</sub>	30	
	T <sub>C</sub> =100°C		21	A
Pulsed Drain Current <sup>(Note 3)</sup>		I <sub>DM</sub>	100	А
Total Power Dissipation	T <sub>C</sub> =25°C	В	20	10/
	T <sub>C</sub> =100°C	P <sub>D</sub>	10	W
Single Pulse Avalanche Energy <sup>(Note 4)</sup>		E <sub>AS</sub>	128	mJ

#### Note

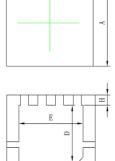
- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. The Maximum Rating Presented Here is Based on Mounting on a 1in<sup>2</sup> Pad of 2oz Copper.
- 3. Pulse Test: Pulse Width ≤300us, Duty Cycle ≤2%.
- 4. TJ=25°C,  $V_{DD}$ =20V,  $V_{G}$ =10V, L=0.5mH,  $R_{g}$ =25 $\Omega$

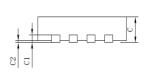
# **Internal Structure and Marking Code**





# DFN3333





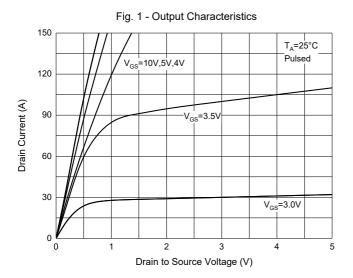
DIMENSIONS					
DIM	INC	HES	MM		NOTE
DIM	MIN	MAX	MIN	MAX	NOTE
Α	0.FG	0.FH€	HÈG€	HÈH€	
В	0.FG	0.FH€	HÈG€	HÈH€	
С	0.0 <b>H</b> €	0.0 <b>H</b>	€ÈÍ	€ÈÍ	
ÔF	0.€€Ï	0.€09	€ÈÌÁ	€ÈGG	
ÔG	Œ	€È€G	Œ	€ÈÉÍ	
Ö	€ÈËÏF	€ÈËÏJ	FÈ€	GÈ€€	
Ò	€ÈÈÏ	€ŒJÌ	ŒŒ	GĚ€	
Ø	€ÈEFÎ	€Ì€G€	€Ì€	0.Í 0	
Õ	€ÈEF€	€ÈEFI	€ÈGÍ	€ÌHÍ	
Р	0.01G	0.016	€ÌH€	€Ì€	
^	0.024	0.028	€Ë€	€Ë€	

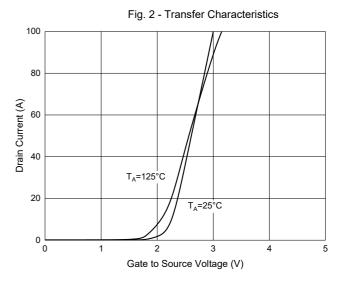


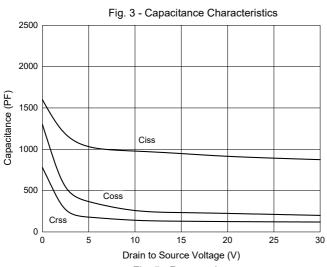
## Electrical Characteristics @ 25°C (Unless Otherwise Specified)

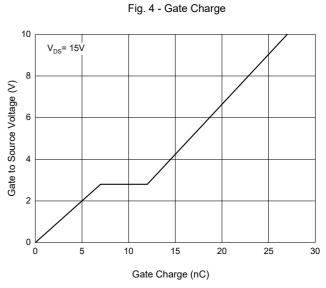
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics	I					I	
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	30			V	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{DS} = 0V, V_{GS} = \pm 20V$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V,T <sub>J</sub> =25°C			1	μΑ	
		V <sub>DS</sub> =30V, V <sub>GS</sub> =0V,T <sub>J</sub> =55°C	5		5		
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1	1.5	2.5	V	
Drain-Source On-Resistance	D	V <sub>GS</sub> =10V, I <sub>D</sub> =15A	8 10		10		
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A		10	13	mΩ	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =15A		0.85	1.2	V	
Maximum Body-Diode Continuous Current	Is				30	Α	
Dynamic Characteristics							
Input Capacitance	C <sub>iss</sub>			1020		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =15V, $V_{GS}$ =0V,f=1MHz		225			
Reverse Transfer Capacitance	C <sub>rss</sub>			126			
Switching Characteristics				,			
Total Gate Charge	$Q_g$			28			
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =10V,I <sub>D</sub> =30A		7		nC	
Gate-Drain Charge	$Q_{gd}$			5			
Reverse Recovery Chrage	Q <sub>rr</sub>	1 454 H. 4004/		25			
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =15A, di/dt=100A/μs		26			
Turn-On Delay Time	t <sub>d(on)</sub>			8			
Turn-On Rise Time	t <sub>r</sub>	$V_{GS}$ =10V, $V_{DS}$ =20V, $I_{D}$ =2A, $R_{L}$ =1 $\Omega$ ,		15		ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{GEN}$ =3 $\Omega$		27			
Turn-Off Fall Time	t <sub>f</sub>			7			

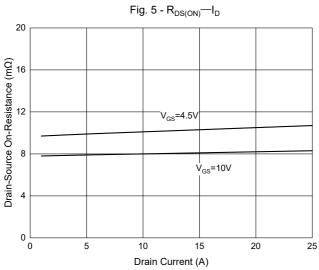


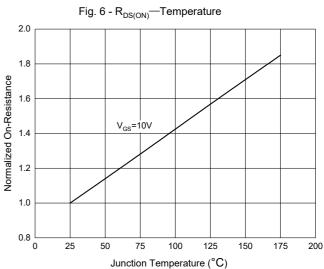














### **Ordering Information**

Device	Packing	
Part Number-TP	Tape&Reel: 5Kpcs/Reel	

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